



Cite this: *RSC Adv.*, 2017, 7, 31597

Optical properties and structural phase transitions of W-doped VO₂(R) under pressure†

Huafang Zhang,^a Zhou Guan,^a Benyuan Cheng,^b Quanjun Li,^{*a} Ran Liu,^a Jing Zhang,^a Zhenxian Liu,^c Ke Yang,^d Tian Cui^{id}^a and Bingbing Liu^{id}^{*a}

We investigated the optical properties and structural phase transitions of W-doped VO₂(R) nanoparticles under pressure based on *in situ* synchrotron X-ray diffraction (XRD) and infrared (IR) spectroscopy. The structural transition sequence follows VO₂(R)–VO₂(CaCl₂-type)–VO₂(Mx) and VO₂(Mx)–VO₂(Mx') within metallic phases, in compression and decompression processes, respectively, demonstrating that the structural transition can be decoupled from the metal-insulator transition (MIT). VO₂(R) and VO₂(CaCl₂-type) exhibit expected behavior of increased metallicity under pressure; surprisingly, VO₂(Mx) shows gradually decreased metallicity with increasing pressure and VO₂(Mx') is still metallic under ambient conditions. We find that the reduced metallicity of VO₂(Mx) is attributed to W-doping induced local structure distortion in the high-pressure region, while the metallic properties of VO₂(Mx') are associated with the enhancement of electron concentration due to the presence of W donors, which shifted the Fermi level toward the conduction band. The present results demonstrate that the structural transition is not the key factor in driving the metal-insulator transition, and provide an effective method for inducing MIT in VO₂(Mx').

Received 24th April 2017

Accepted 2nd June 2017

DOI: 10.1039/c7ra04605g

rsc.li/rsc-advances

Introduction

Vanadium dioxide (VO₂) is a typical strongly correlated material with different polymorphs, including the tetragonal VO₂(R), VO₂(A) and VO₂(C),^{1–3} and the monoclinic VO₂(M1), VO₂(B), and VO₂(D).^{4–6} Changes in the structure and physical properties in the VO₂ system can be induced by controlling temperature. For example, VO₂ undergoes a reversible MIT at about 68 °C, accompanied with a structural transition from VO₂(R) to VO₂(M1), and huge changes in physical properties of electrical resistivity, infrared transmittance and magnetic susceptibility, which make this material potentially useful for intelligent devices.^{1,7,8} Moreover, VO₂ also shows a reversible MIT between the semiconducting VO₂(A) and a new metallic tetragonal structure (VO₂(A_H)) at about 162 °C, and the VO₂(A_H) transforms into the well-known metallic VO₂(R) at about 450 °C.^{9,10} The semiconducting VO₂(B) and VO₂(D) transform directly into the metallic VO₂(R) at about 500 °C and 320 °C, respectively.^{6,11} As the thermally driven MIT in the strongly correlated VO₂ system is always accompanied by a structural transition, remarkable

experimental and theoretical efforts have been devoted to addressing the role of structural transformation and electron–electron correlation in driving the MIT,^{12–16} but the mechanism is still under debate.

Pressure, an important tuning parameter, which can effectively reduce atom distances and increase electron orbital overlaps, has great influence on the structure and physical properties on materials.^{17–19} In recent years, lots of high pressure investigations have been carried out on VO₂ systems and found that VO₂ in different polymorphs show unique structural phase transition and physical properties under pressure.^{20–32} The phase transition sequence of VO₂(M1) follows M1–M1'–X/Mx, Mx–Mx' in compression and decompression process, respectively,^{23,30–32} the M1' phase is semiconductor within low pressure region but becomes metallic above 43.2 GPa. Different with VO₂(M1), the VO₂(A) and VO₂(B) transform directly into an amorphous state under pressure,^{28,29} in particular, VO₂(A) being metallic before amorphization due to the delocalization of V_{3d} orbital electrons, whereas VO₂(B) remains a semiconductor before and after amorphization. These studies on semiconducting VO₂ polymorphs suggest that the MIT may occur without structural transition under pressure. In addition, the study on the structural transition of the metallic VO₂(R) at 383 K indicates that VO₂(R) transforms into an orthorhombic structure (VO₂(CaCl₂-type)) at about 13.3 GPa, and then starts to transform into a new monoclinic structure (VO₂(X)) at about 38.6 GPa.³⁰ According to previous study on metallic V₂O₃,³³ another typical MIT system, for which the thermal-driven MIT always accompanied with a structure transformation from

^aState Key Laboratory of Superhard Materials, Jilin University, Changchun 130012, China. E-mail: liubb@jlu.edu.cn; liquanjun@jlu.edu.cn; Fax: +86-431-85168256; +86 18043176111; Tel: +86-431-85168256; +86 18043176111

^bChina Academy of Engineering Physics, Mianyang, Sichuan, 621900, China

^cU2A Beam Line, Carnegie Institution of Washington, Upton, New York 11973, USA

^dChinese Academy Sciences, Shanghai Institute Applied Physics, Shanghai 201204, China

† Electronic supplementary information (ESI) available. See DOI: 10.1039/c7ra04605g



a corundum structure into a monoclinic phase, the corundum-to-monoclinic transformation occurs between two metallic phases under pressure, demonstrating that the structural transition can be decoupled from the MIT. These results suggest the possibility of decoupling MIT from structural transition in metallic VO₂(R) phase under pressure, however, no efforts have been performed on the electrical study on the metallic VO₂(R) under pressure.

As is known, the R-to-M1 transition temperature (T_c) can be reduced by doping with transition metal, such as W⁶⁺, Mo⁶⁺, and Nb⁵⁺.^{34–39} Among these, the most exciting prospective way would be the W-doping, which enabling precise and wide range control of T_c , with a nearly linear reduction rate of 18.4–26 °C/at%,^{34,37–39} providing experimental base for high pressure research on VO₂(R). Infrared spectroscopy, as a powerful tool to probe the dynamics of charge carriers, has been widely used in the high-pressure study on strong correlated materials.^{40–43} In this study, we present the measurements of infrared properties and structure phase transitions of W-VO₂(R) under pressure up to 63.9 GPa. We found a pressure induced rutile–orthorhombic–monoclinic transitions in three metallic phases, and obtained a metallic W-VO₂(Mx') (W-VO₂(Mx')) at ambient conditions.

Experimental

Synthesis

W-VO₂(R) nanoparticles were synthesized through hydrothermal reaction combined with subsequent calcinations. In a typical procedure, 0.2275 g V₂O₅, 0.3938 g oxalic acid and 0.0824 g Na₂WO₄·2H₂O were added to 100 ml deionized water, and followed by vigorous stirring until a pale-yellows solution was formed. The solution was transferred into a Teflon-lined autoclave with the filling ratio of 0.6, and held at 190 °C for 24 h. The precipitate was collected by centrifugal separation, washed with deionized water and alcohol and dried in vacuum freezing dryer. The resulted powers were calcined at 600 °C for 3 h in argon atmosphere.

Characterization

Samples were characterized using transmission electron microscopy (TEM) (200 KV, HITACHI, H-81001V), and high-resolution transmission electron microscopy (HRTEM) (JEOL JEM-3010). High-pressure XRD and IR experiments were carried out by using diamond anvil cells (DACs). The T301 stainless-steel gaskets were preindented to 40–50 μm and drilled with a center hole of ~100 μm as sample chamber. High-pressure XRD use a 4 : 1 methanol–ethanol mixture as pressure-transmitting medium. High-pressure IR measurements were carried out using pure sample. The ruby fluorescence technique was used to calibrate pressures for all experiments. The *in situ* high pressure synchrotron XRD measurements were performed at the BL15U beamline of Shanghai Synchrotron Radiation Facility (SSRF) ($\lambda = 0.6199 \text{ \AA}$). The high-pressure IR spectra were collected through a Bruker Vertex 80v FTIR spectrometer and a microscope/a Hyperion 2000 IR microscope equipped with a liquid nitrogen cooled MCT detector.

The optical reflectivity of sample–diamond interface $R_{sd}(\omega)$ was obtained by the following equation:⁴⁴

$$R_{sd}(\omega) = \frac{I_{sd}(\omega)}{I_e(\omega)} \cdot \frac{I_d(\omega)}{I_0(\omega)} \quad (1)$$

where $I_{sd}(\omega)$ and $I_d(\omega)$ are the intensities reflected from the sample–diamond interface and the air–diamond interface at each pressure, respectively. $I_e(\omega)$ and $I_0(\omega)$ are the intensities reflected from empty cell and air–gold foil interface, respectively.

Results

Pressure-dependent IR spectra

The characterizations for the structure and morphology of synthesized W-doped samples are shown in Fig. S1,[†] all the diffraction peaks can be indexed to VO₂(R), indicating that the W-doped samples are pure VO₂(R) nanoparticles with average diameter of 100–200 nm. To investigate the electronic changes for W-VO₂(R) nanoparticles under pressure, we performed high pressure mid-IR reflectivity $R_{sd}(\omega)$ spectra measurements (shown in Fig. 1). The data between 1700 cm⁻¹ and 2700 cm⁻¹ were cut out from $R_{sd}(\omega)$ spectra due to the absorption of diamond. At ~1.9 GPa, $R_{sd}(\omega)$ is slightly lower than expected for sample–air interface due to the larger refractive index value in diamond.^{40,45} With increasing pressure, $R_{sd}(\omega)$ gradually

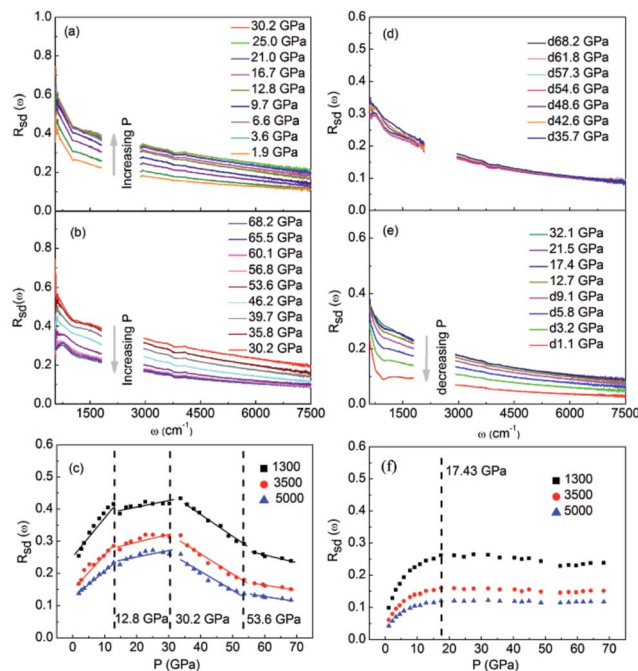


Fig. 1 IR reflectivity spectra of W-VO₂ nanoparticles upon compression in the pressure region of (a) 1.9–30.2 GPa and (b) 30.2–68.2 GPa, (c) pressure–reflectivity diagram of three different wave numbers (1300, 3500 and 3000 cm⁻¹) upon compression. IR reflectivity spectra of W-VO₂ nanoparticles upon decompression in the pressure region of (d) 68.2–35.7 GPa and (e) 32.1–1.1 GPa, (f) pressure–reflectivity diagram for three different wave numbers (1300, 3500 and 3000 cm⁻¹) upon decompression.



increases up to 12.8 GPa, and then shows almost no change in the 12.8–30.2 GPa range. Surprisingly, $R_{sd}(\omega)$ starts to decrease above 30.2 GPa, and then decrease more subtle when the pressure is beyond 53.6 GPa. This unexpected behavior above 30.2 GPa has not been observed in VO₂ system before. According to early study, the reflectivity in terms of dielectric constant ($\sqrt{\epsilon(\omega)}$) at normal incidence is given by⁴⁵

$$R(\omega) = \left| \frac{\sqrt{\epsilon(\omega)} - 1}{\sqrt{\epsilon(\omega)} + 1} \right|^2 \quad (2)$$

The $\sqrt{\epsilon(\omega)}$ has the following form

$$\epsilon(\omega) = \epsilon_\infty - \frac{\omega_n^2}{\omega^2 + i\omega_c\omega} + \sum_{i=1}^n \frac{s_i}{1 - \frac{\omega^2}{\omega_i^2} - \frac{i\Gamma_i\omega}{\omega_i}} \quad (3)$$

where ϵ_∞ represents a contribution to the real part of $\epsilon(\omega)$ from high-frequency electronic transitions, $\frac{\omega_n^2}{\omega^2 + i\omega_c\omega}$ represents the contribution to $\epsilon(\omega)$ from free-electron, ω_n and ω_c are the carrier density parameter and collision frequency, respectively. The last term is the sum over Lorentz, classical oscillators that contribute to the nonconstant part of $\epsilon(\omega)$. In low-frequency, the reflectivity of the R phase is characterized by a continuous rise due to the free-electronic contribution.^{46,47} The higher reflectivity in low-frequency region, indicates higher carrier density in measured samples. Therefore, the pressure dependence of the IR reflectivity at low frequencies gives the electronic evolution under pressure, qualitatively. As shown in Fig. 1c, the reflectivity at low frequencies increases gradually owing to a larger bandwidth up to 12.8 GPa, but show a noticeable change in slope at about 12.8 GPa, which could be related to the structural phase transition of VO₂(R)-to-VO₂(CaCl₂-type) observed in early XRD study on pure VO₂(R).³⁰ When pressure is above 30.2 GPa, the reflectivity starts to decrease, but then decreases more sluggish with further compressing above 53.6 GPa, suggesting the metallicity decreases in W-VO₂ under higher pressure. These results show pressure makes our sample more metallic only up to 30.2 GPa. According to early study, the IR spectroscopy decisively depends on the configuration of atoms,⁴⁸ therefore, the unexpected decrease of IR reflectivity should be mainly related to the accompanying change in crystal structure under pressure.

Upon decompression, $R_{sd}(\omega)$ exhibits subtle change up to 17.4 GPa (Fig. 1d and e). With further decompressing, $R_{sd}(\omega)$ starts to decrease significantly. When the applied pressure decreased to 1.1 GPa, the reflectivity is clearly lower than that of initial W-VO₂(R) phase (Fig. 1a and e). Similar behaviors are observed in the pressure-reflectivity diagram for wave numbers at 1300, 3500 and 3000 cm⁻¹. These results suggest that the metallicity is independent with pressure above 17.4 GPa, but decreases with pressure upon further decompressing.

For clarifying that whether W-VO₂ nanoparticles in different pressure regions are metallic or not, we carried out high pressure transmittance spectra measurements on both W-VO₂ and pure VO₂ (shown in Fig. 2). The data between 1700 cm⁻¹ and

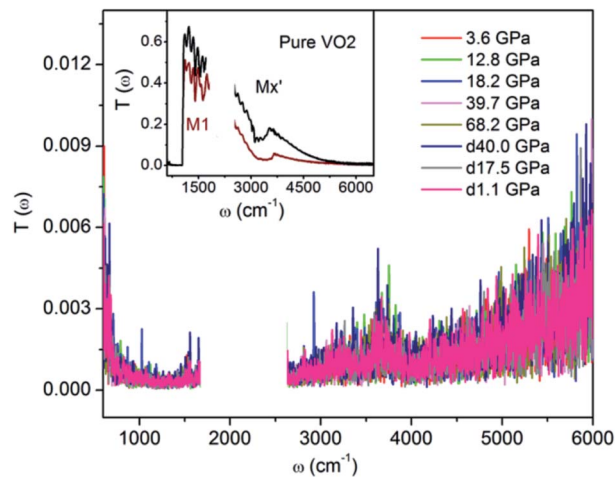


Fig. 2 IR transmittance spectra of W-VO₂ nanoparticles at selected pressures. Inset: IR transmittance spectrum of insulating M1 and Mx' phases in pure VO₂.

2700 cm⁻¹ were cut out from $R_{sd}(\omega)$ spectra due to the absorption of diamond. Compared with the transmittance spectra of the insulating VO₂(M1) and the quenched VO₂(Mx') in pure VO₂ (inset of Fig. 2), which present maxima in IR transmittance at around 1000 cm⁻¹, there is no transmitted light in the whole spectrum in W-VO₂ under various pressures. These results clearly identify that W-VO₂ is metallic in whole pressure region.

Pressure-dependent XRD patterns

To have a better understanding of the changes in the metallicity of W-VO₂(R) under pressure, we carried out high pressure XRD measurements in characterizing the crystal structural transition up to 63.9 GPa (shown in Fig. 3). In the low pressure range (0–13.5 GPa), all diffraction peaks shift toward smaller d -spacings

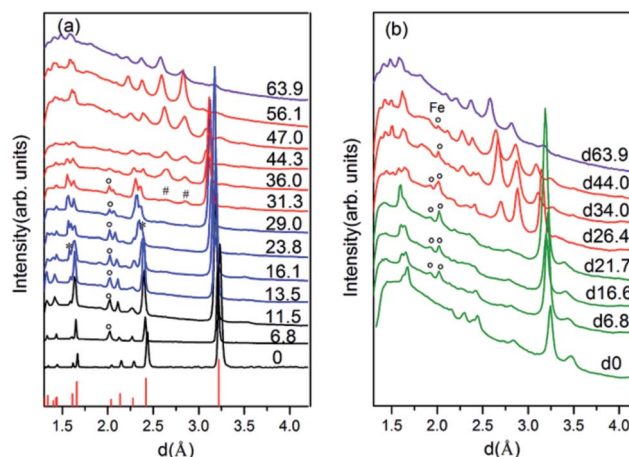


Fig. 3 XRD patterns of W-VO₂(R) nanoparticles at various pressures, (a) collected upon compression, (b) collected upon decompression. Diffraction peaks marked "*", "#", and "o" originate from VO₂(CaCl₂-type), VO₂(Mx) and Fe, respectively. The lines at the bottom of (a) correspond to the diffraction peaks of VO₂(R) taken from PDF no. 79-1655.



due to lattice compression, without modifications of the overall diffraction pattern. Above 13.5 GPa, some diffraction peaks start to broaden or split (denoted by stars), indicating a structural transition from R into an orthorhombic CaCl_2 -type phase, which is consistent with previous study on pure $\text{VO}_2(\text{R})$.³⁰ With further increasing pressure above 31.3 GPa, several new peaks (marked with "#") appear, suggesting the occurrence of the structural transition from CaCl_2 -type phase into a new high-pressure phase. At 63.9 GPa, the CaCl_2 -type phase completely transforms into the new high-pressure phase. The structure of the high-pressure phase is still unclear. The diffraction pattern of the high-pressure phase is clearly different from that of X phase in bulk VO_2 ,^{30,31} but similar to that of the Mx phase in VO_2 nanoparticles (Fig. 4a).³² Therefore, a monoclinic unit cell with space group $P2_1/c$ was used to fit the measured XRD pattern at 63.9 GPa. As shown in Fig. 4b, the fitting gives relatively satisfying results, with $R_{\text{wp}} = 0.48\%$, $R_p = 0.36\%$. The lattice parameters are listed in Table 1. Note that the onset and finish pressures of the structural transition from the CaCl_2 -type to the high-pressure Mx phase agree well with the pressures of the slope change in IR reflectivity (Fig. 1c). This indicates the electric change of W-VO_2 depends on its structural transition behaviors under high pressure.

Upon decompression, a new peak appears at $\sim 3.09 \text{ \AA}$ when the pressure decreases to $\sim 44.0 \text{ GPa}$, indicating a structural transition from $\text{VO}_2(\text{Mx})$ phase into a new structure (shown in Fig. 3b). With further decreasing pressure, all the diffraction peaks of $\text{VO}_2(\text{Mx})$ phase gradually weaken and finally disappear at $\sim 21.7 \text{ GPa}$, showing that all the $\text{VO}_2(\text{Mx})$ samples transform into the new phase. We note that this structural transition process is rather sluggish, with the two phases coexist spanning over 20 GPa, demonstrating that this structural transformation is kinetically hindered. The XRD pattern of the released sample

Table 1 Parameters for Mx and Mx' phases in W doped and pure VO_2 nanoparticles

Phase	a (\AA)	b (\AA)	c (\AA)	V (\AA^3)	Reference
W-Mx	4.434	4.741	4.918	102.645	This study
Mx	4.468	4.693	4.744	98.699	Ref. 32
W-Mx'	4.681	5.324	6.336	154.792	This study
Mx'	4.631	5.308	6.394	151.820	Ref. 32

is similar to that of Mx' phase in pure VO_2 nanoparticles³² (shown in Fig. 4c), therefore, a monoclinic structure with the same space group $P2_1/c$ were used to refine it. The results of Rietveld refinements are shown in Fig. 4d, with $R_{\text{wp}} = 0.50\%$, $R_p = 0.35\%$, and the obtained cell parameters are listed in Table 1. Both of the cell parameters and cell volume V are close to those of pure counterparts,³² suggesting that W-doping induces only subtle modifications in crystal structure of the released sample. It is interesting that the quenched W-VO_2 samples are metallic at ambient conditions. Thus, these results demonstrate the W-doping induced MIT in $\text{VO}_2(\text{Mx}')$ without structural phase transition. The structural phase transitions of rutile-orthorhombic-monoclinic and monoclinic-monoclinic in metallic phases in compressing and decompressing processes, respectively, and the doping-induced MIT in $\text{VO}_2(\text{Mx}')$ indicate that the structural transition can be decoupled from MIT.

Discussion

The pressure dependence of reflectivity in the R phase (Fig. 1c) indicates that pressure makes the R phase more metallic. Within the 0–13.5 GPa range, the isotropic compression in the R phase resulted in a continuous decrease in cell volume (Fig. 3). So the $\text{W-VO}_2(\text{R})$ follows the expected behavior of increased metallicity due to larger bandwidth.³³ In the pressure range of 12.8–30.2 GPa, the reflectivity is high and show subtle changes within the crystal structure of the CaCl_2 -type phase, indicating that CaCl_2 -type phase show better metallicity than the R phase. It is worth noting that the metallicity gradually decreases with further compressing above 30.2 GPa, accompanied with a structural transformation from the CaCl_2 -type phase into the high-pressure Mx phase, indicates that the high-pressure Mx phase in W-VO_2 nanoparticles is less metallic. As the W-Mx phase has the same crystal structure with pure the Mx phase, we made a comparison on the metallicity of these samples (shown in Fig. 5). The reflectivity of the W-Mx is much lower than that of the pure Mx, suggesting that the W-doping makes Mx phase less metallic. Although the W-Mx and pure Mx phases show similar XRD patterns, we note that the diffraction peaks in the W-Mx phase is broader and weaker than that of the pure Mx phase (Fig. 4a), moreover, the lattice parameter c and the cell volume V of the W-Mx phase are larger than that of pure Mx phase (Table 1). These results suggest that W-doping induced disorder of local structure was probably formed in W-Mx. According to previous study, the W-doping induced disorder in $\text{VO}_2(\text{R})$ results in an obvious increase in resistivity.⁴⁹ So the poor

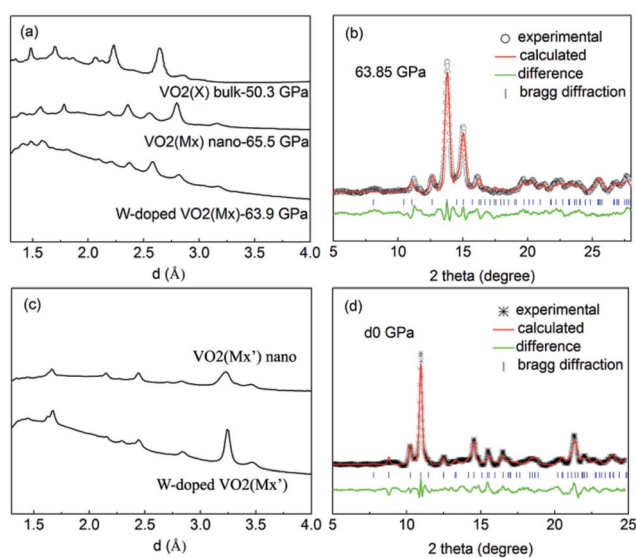


Fig. 4 The XRD patterns of (a) $\text{W-VO}_2(\text{Mx})$ nanoparticles, $\text{VO}_2(\text{Mx})$ nanoparticles and bulk $\text{VO}_2(\text{X})$, (c) $\text{W-VO}_2(\text{Mx}')$ and $\text{VO}_2(\text{Mx}')$ nanoparticles. Refinement results of (b) $\text{W-VO}_2(\text{Mx})$ nanoparticles at 63.9 GPa, (d) $\text{W-VO}_2(\text{Mx}')$ nanoparticles at ambient pressure.



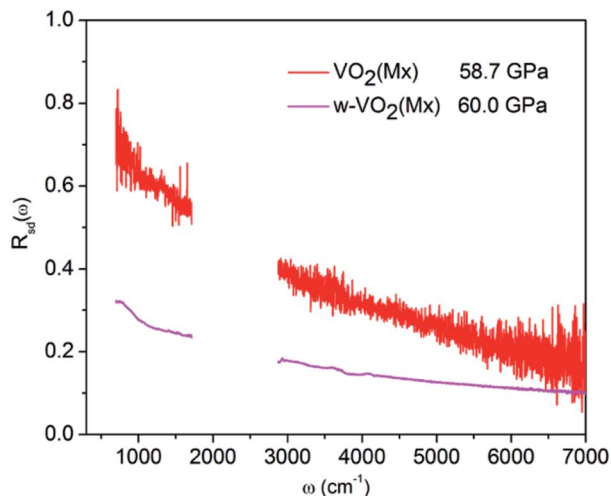


Fig. 5 IR reflectivity spectra of the Mx phase for W-doped and pure VO₂ nanoparticles.

metallicity in the W-Mx phase is likely related to W-doping induced disorder of local structure.

Upon decompression, the structural transition from the W-Mx to W-Mx' phase starts from ~ 44 GPa and completed at about 21.7 GPa, whereas the metallicity is independent of applied pressure above 17.4 GPa, suggests that the metallicity of these two phases are stable in the high pressure region. When released to ambient pressure, the W-Mx' phase shows remarkable decreased metallicity but is still metallic, in contrast to the insulator Mx' phase in pure VO₂ nanoparticles (shown in the inset of Fig. 2). These results indicates that W-doping induced MIT occurs in the Mx' phase. Compared with the W-doping induced MIT in M1 phase, which accompanied with a structural transformation from the M1 to R phase, the MIT in the Mx' phase occurs without structural transition. Previous studies have indicated that the presence of W donors enhance the electron concentration in VO₂,^{50–53} which could shifts the Fermi level toward conduction band and resulting in the MIT. These results not only pave an effective method for modifying electronic properties of VO₂ new structure, but also provide further insight into the MIT of VO₂.

Conclusion

We have investigated the structural phase transitions and optical properties on W-doped VO₂(R) nanoparticles under pressure. Compared with the temperature-dependent study on VO₂, where rutile–monoclinic structural transition always coincides with MIT, the structural transitions of rutile–orthorhombic–monoclinic occur within metallic phases under pressure. Moreover, we find a W-doping induced MIT in VO₂(Mx') without structural transitions. We suggest that the decreased metallicity in Mx phase under pressure can be attributed to the W-doping induced local structure distortion, and the MIT of Mx' phase may results from the enhancement of electron concentration due to the presence of W donors, which shifted the Fermi level toward the conduction band. Present results

demonstrate that structural transition is not the key factor in driving metal-insulator transition, and paves an effective method for modifying electronic properties of VO₂ new structure.

Acknowledgements

This work was financially supported by the NSFC (11374120 and 51320105007), National Basic Research Program of China (2011CB808200), Program for Changjiang Scholars and Innovative Research Team in University (No. IRT1132), and the Cheung Kong Scholars Programme of China.

References

- 1 F. J. Morin, *Phys. Rev. Lett.*, 1959, **3**, 34–36.
- 2 F. Théobald, *J. Less-Common Met.*, 1977, **53**, 55–71.
- 3 D. Hagrman, J. Zubieta, C. J. Warren, L. M. Meyer, M. M. J. Treacy and R. C. Haushalter, *J. Solid State Chem.*, 1998, **138**, 178–182.
- 4 G. Andersson, *Acta Chem. Scand.*, 1954, **8**, 1599–1606.
- 5 F. Théobald, R. Cabala and J. Bernard, *J. Solid State Chem.*, 1976, **17**, 431–438.
- 6 L. Liu, F. Cao, T. Yao, Y. Xu, M. Zhou, B. Qu, B. Pan, C. Wu, S. Wei and Y. Xie, *New J. Chem.*, 2012, **36**, 619–625.
- 7 K. W. Lee, J. J. Kweon, C. E. Lee, A. Gedanken and R. Ganesan, *Appl. Phys. Lett.*, 2010, **96**, 243111.
- 8 J. Zhou, Y. Gao, Z. Zhang, H. Luo, C. Cao, Z. Chen, L. Dai and X. Liu, *Sci. Rep.*, 2013, **3**, 3029.
- 9 T. Yao, Y. Oka and N. Yamamoto, *J. Solid State Chem.*, 1994, **112**, 196–198.
- 10 S. Zhang, B. Shang, J. Yang, W. Yan, S. Wei and Y. Xie, *Phys. Chem. Chem. Phys.*, 2011, **13**, 15873–15881.
- 11 X. Xiao, H. Cheng, G. Dong, Y. Yu, L. Chen, L. Miao and G. Xu, *CrystEngComm*, 2013, **15**, 1095–1106.
- 12 R. M. Wentzcovitch, W. W. Schulz and P. B. Allen, *Phys. Rev. Lett.*, 1994, **72**, 3389–3392.
- 13 M. M. Qazilbash, M. Brehm, B. G. Chae, P. C. Ho, G. O. Andreev, B. J. Kim, S. J. Yun, A. V. Balatsky, M. B. Maple, F. Keilmann, H. T. Kim and D. N. Basov, *Science*, 2007, **318**, 1750–1753.
- 14 J. B. Goodenough, *J. Solid State Chem.*, 1971, **3**, 490.
- 15 M. W. Haverkort, Z. Hu, A. Tanaka, W. Reichelt, S. V. Streltsov, M. A. Korotin, V. I. Anisimov, H. H. Hsieh, H. J. Lin, C. T. Chen, D. I. Khomskii and L. H. Tjeng, *Phys. Rev. Lett.*, 2005, **95**, 196404.
- 16 T. C. Koethe, Z. Hu, M. W. Haverkort, C. Schussler-Langeheine, F. Venturini, N. B. Brookes, O. Tjernberg, W. Reichelt, H. H. Hsieh, H. J. Lin, C. T. Chen and L. H. Tjeng, *Phys. Rev. Lett.*, 2006, **97**, 116402.
- 17 C. C. Chen, A. Herhold, C. Johnson and A. Alivisatos, *Science*, 1997, **276**, 398–401.
- 18 R. E. Cohen, I. I. Mazin. and D. G. Isaak, *Science*, 1997, **275**, 654–657.
- 19 A. Togo, F. Oba and I. Tanaka, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2008, **78**, 134106.



- 20 C. H. Neuman, A. W. Lawson and R. F. Brown, *J. Chem. Phys.*, 1964, **41**, 1591–1595.
- 21 C. N. Berglund and A. Jayaraman, *Phys. Rev.*, 1969, **185**, 1034–1039.
- 22 E. Arcangeletti, L. Baldassarre, D. Di Castro, S. Lupi, L. Malavasi, C. Marini, A. Perucchi and P. Postorino, *Phys. Rev. Lett.*, 2007, **98**, 196406.
- 23 M. Mitrano, B. Maroni, C. Marini, M. Hanfland, B. Joseph, P. Postorino and L. Malavasi, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2012, **85**, 184108.
- 24 C. Marini, E. Arcangeletti, D. Di Castro, L. Baldassarre, A. Perucchi, S. Lupi, L. Malavasi, L. Boeri, E. Pomjakushina, K. Conder and P. Postorino, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2008, **77**, 235111.
- 25 M. Baldini, P. Postorino, L. Malavasi, C. Marini, K. W. Chapman and H. k. Mao, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2016, **93**, 245137.
- 26 X. Zhang, J. Zhang, F. Ke, G. Li, Y. Ma, X. Liu, C. Liu, Y. Han, Y. Ma and C. Gao, *RSC Adv.*, 2015, **5**, 54843–54847.
- 27 W. P. Hsieh, M. Trigo, D. A. Reis, G. Andrea Artioli, L. Malavasi and W. L. Mao, *Appl. Phys. Lett.*, 2014, **104**, 021917.
- 28 B. Cheng, Q. Li, H. Zhang, R. Liu, B. Liu, Z. Yao, T. Cui, J. Liu, Z. Liu, B. Sundqvist and B. Liu, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2016, **93**, 184109.
- 29 Y. Wang, J. Zhu, W. Yang, T. Wen, M. Pravica, Z. Liu, M. Hou, Y. Fei, L. Kang, Z. Lin, C. Jin and Y. Zhao, *Nat. Commun.*, 2016, **7**, 12214.
- 30 L. Bai, Q. Li, S. A. Corr, Y. Meng, C. Park, S. V. Sinogeikin, C. Ko, J. Wu and G. Shen, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2015, **91**, 104110.
- 31 H. Zhang, Q. Li, B. Cheng, Z. Guan, R. Liu, B. Liu, Z. Liu, X. Li, T. Cui and B. Liu, *RSC Adv.*, 2016, **6**, 104949–104954.
- 32 Q. Li, H. Zhang, C. Lin, F. Tian, J. S. Smith, C. Park, B. Liu and G. Shen, *J. Alloys Compd.*, 2017, **709**, 260–266.
- 33 Y. Ding, C. C. Chen, Q. Zeng, H. S. Kim, M. J. Han, M. Balasubramanian, R. Gordon, F. Li, L. Bai, D. Popov, S. M. Heald, T. Gog, H. K. Mao and M. van Veenendaal, *Phys. Rev. Lett.*, 2014, **112**, 056401.
- 34 Q. Gu, A. Falk, J. Wu, L. Ouyang and H. Park, *Nano Lett.*, 2007, **7**, 363–366.
- 35 Z. P. Wu, A. Miyashita, S. Yamamoto, H. Abe, I. Nashiyama, K. Narumi and H. Naramoto, *J. Appl. Phys.*, 1999, **86**, 5311–5313.
- 36 C. Piccirillo, R. Binions and I. P. Parkin, *Eur. J. Inorg. Chem.*, 2007, 4050–4055.
- 37 P. Jin, S. Nakao and S. Tanemura, *Thin Solid Films*, 1998, **324**, 151–158.
- 38 J. C. Rakotoniaina, R. Mokrani-Tamellin, J. R. Gavarri, G. Vacquier, A. Casalot and G. J. Calvarin, *Solid State Chem.*, 1993, **103**, 81–94.
- 39 T. Hörlin, T. Niklewski and M. Nygren, *Mater. Res. Bull.*, 1972, **7**, 1515–1524.
- 40 L. Baldassarre, A. Perucchi, E. Arcangeletti, D. Nicoletti, D. Di Castro, P. Postorino, V. A. Sidorov and S. Lupi, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2007, **75**, 245108.
- 41 Y. Mita, D. Izaki, M. Kobayashi and S. Endo, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2005, **71**, 100110.
- 42 M. Matsunami, H. Okamura, A. Ochiai and T. Nanba, *Phys. Rev. Lett.*, 2009, **103**, 237202.
- 43 A. Perucchi, L. Baldassarre, P. Postorino and S. Lupi, *J. Phys.: Condens. Matter*, 2009, **21**, 323202.
- 44 C. T. Seagle, D. L. Heinz, Z. Liu and R. J. Hemley, *Appl. Opt.*, 2009, **48**, 545–552.
- 45 H. W. Verleur, A. S. Barker and C. N. Berglund, *Phys. Rev.*, 1968, **172**, 788–798.
- 46 M. Kang, S. W. Kim, J. W. Ryu and T. Noh, *AIP Adv.*, 2012, **2**, 012168.
- 47 M. M. Qazilbash, M. Brehm, G. O. Andreev, A. Frenzel, P. C. Ho, B. G. Chae, B. J. Kim, S. J. Yun, H. T. Kim, A. V. Balatsky, O. G. Shpyrko, M. B. Maple, F. Keilmann and D. N. Basov, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2009, **79**, 075107.
- 48 Y. Sun, S. Jiang, W. Bi, R. Long, X. Tan, C. Wu, S. Wei and Y. Xie, *Nanoscale*, 2011, **3**, 4394–4401.
- 49 K. Shibuya, M. Kawasaki and Y. Tokura, *Appl. Phys. Lett.*, 2010, **96**, 022102.
- 50 X. Tan, T. Yao, R. Long, Z. Sun, Y. Feng, H. Cheng, X. Yuan, W. Zhang, Q. Liu, C. Wu, Y. Xie and S. Wei, *Sci. Rep.*, 2012, **2**, 466.
- 51 C. Wu, F. Feng, J. Feng, J. Dai, L. Peng, J. Zhao, J. Yang, C. Si, Z. Wu and Y. Xie, *J. Am. Chem. Soc.*, 2011, **133**, 13798–13801.
- 52 L. Q. Mai, B. Hu, T. Hu, W. Chen and E. D. J. Gu, *Phys. Chem. B.*, 2006, **110**, 19083–19086.
- 53 W. Choi, A. Termin and M. R. Hoffmann, *J. Phys. Chem.*, 1994, **98**, 13669–13679.

